

## **FFPF10F150S**

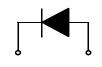
### **Features**

- High voltage and high reliability
- High speed switching
- Low forward voltage

### **Applications**

• Suitable for damper diode in horizontal deflection circuits





1. Cathode

2. Anode

## **DAMPER DIODE**

## Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>RRM</sub>	Peak Repetitive Reverse Voltage	1500	V
I <sub>F(AV)</sub>	Average Rectified Forward Current @ T <sub>C</sub> = 125°C	10	Α
I <sub>FSM</sub>	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	100	А
T <sub>J,</sub> T <sub>STG</sub>	Operating Junction and StorageTemperature	- 65 to +150	°C

### **Thermal Characteristics**

Symbol		Parameter	Value	Units
	R <sub>B,IC</sub> Maximum Thermal Resistance, Junction to Case		3.0	°C/W

## Electrical Characteristics T<sub>C</sub>=25 °C unless otherwise noted

Symbol	Parameter		Min.	Тур.	Max.	Units
V <sub>FM</sub> *	Maximum Instantaneous Forward Voltage					V
	I <sub>F</sub> = 10A	$T_C = 25 ^{\circ}C$	-	-	1.6	
	I <sub>F</sub> = 10A	$T_C = 25 ^{\circ}C$ $T_C = 125 ^{\circ}C$	-	-	1.4	
I <sub>RM</sub> *	Maximum Instantaneous Reverse Current					μΑ
	@ rated V <sub>R</sub>	$T_C = 25  ^{\circ}C$	-	-	10	
		$T_C = 25  ^{\circ}C$ $T_C = 125  ^{\circ}C$	-	-	80	
t <sub>rr</sub>	Maximum Reverse Recovery Time (I <sub>F</sub> =1A, di/dt = 50A/μs)		-	-	170	ns
+.	Maximum Forward Recovery Time				250	ns
t <sub>fr</sub>	$(I_F = 6.5A, di/dt = 50A/\mu s)$		-	_	230	115
$V_{FRM}$	Maximum Forward Recovery Voltage		-	-	14	V

<sup>\*</sup> Pulse Test: Pulse Width=300µs, Duty Cycle=2%

## **Typical Characteristics**

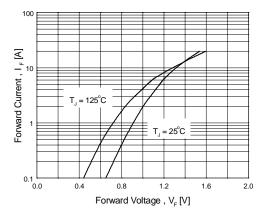


Figure 1. Typical Forward Voltage Drop vs. Forward Current

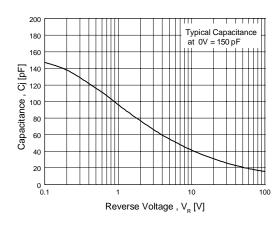


Figure 3. Typical Junction Capacitance

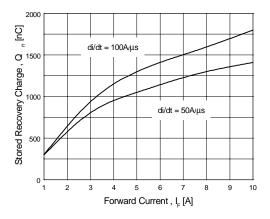


Figure 5. Typical Stored Charge vs. Forward Current

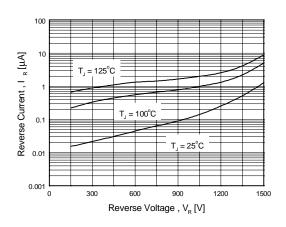


Figure 2. Typical Reverse Current vs. Reverse Voltage

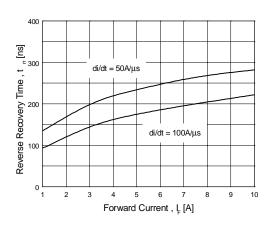


Figure 4. Typical Reverse Recovery Time vs. Forward Current

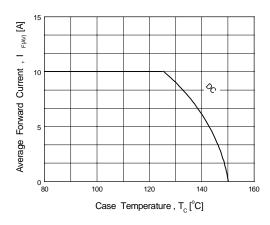
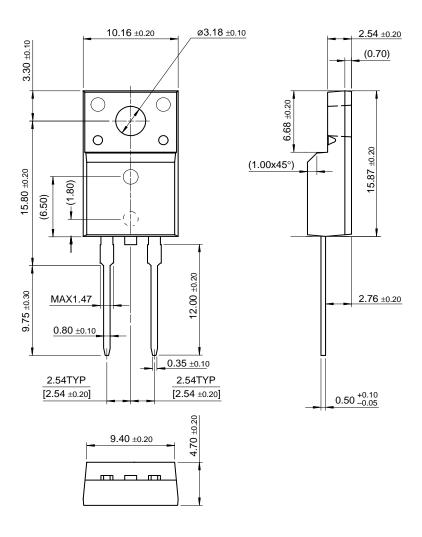


Figure 6. Forward Current Derating Curve

# **Package Dimensions**

# TO-220F 2L



**Dimensions in Millimeters** 

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